

20A, 35V - 150V Schottky Barrier Surface Mount Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- · High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

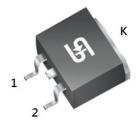
- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS						
PARAMETER VALUE UNI						
I _F	20	Α				
V_{RRM}	35 - 150	V				
I _{FSM}	150 A					
T _{J MAX}	150 °C					
Package	TO-263AB (D ² PAK)					
Configuration	Dual dies					

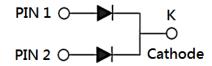








TO-263AB (D²PAK)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	2035	2045	2050	2060	2090	20100	20150	UNIT
		CT	CT	CT	CT	CT	CT	CT	
Marking code on the device		MBRS 2035CT	MBRS 2045CT	MBRS 2050CT	MBRS 2060CT	MBRS 2090CT	MBRS 20100CT	MBRS 20150CT	
Repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	$V_{R(RMS)}$	24	31	35	42	63	70	105	V
Forward current	I _F				20				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}		150						Α
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		1 0.5						Α
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	20				А			
Critical rate of rise of off- state voltage	dv/dt				10,000)			V/µs

Notes:

1. $tp = 2.0\mu s$, 1.0KHz



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MBRS 2035 CT	MBRS 2045 CT	MBRS 2050 CT	MBRS 2060 CT	MBRS 2090 CT	MBRS 20100 CT	MBRS 20150 CT	UNIT
Junction temperature	T_J	-55 to +150					°C		
Storage temperature	T _{STG}	-55 to +150					°C		

THERMAL PERFORMANCE							
PARAMETER		SYMBOL	TYP	UNIT			
Junction-to-case thermal resistance	MBRS2035CT MBRS2045CT MBRS2050CT MBRS2060CT	R _{eJC}	1.5	°C/W			
Junction-to-case thermal resistance	MBRS2090CT MBRS20100CT MBRS20150CT	R _{eJC}	2	°C/W			

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRS2035CT MBRS2045CT	I _F = 10A, T _J = 25°C		-	0.65	V
	MBRS2050CT MBRS2060CT			-	0.80	V
	MBRS2090CT MBRS20100CT			-	0.85	V
	MBRS20150CT			-	0.99	V
	MBRS2035CT MBRS2045CT	I _F = 20A, T _J = 25°C		-	0.84	V
	MBRS2050CT MBRS2060CT		V _F	1	0.95	V
	MBRS2090CT MBRS20100CT			-	0.95	V
Forward voltage per	MBRS20150CT			-	1.23	V
diode ⁽¹⁾	MBRS2035CT MBRS2045CT			-	0.57	V
	MBRS2050CT MBRS2060CT	I _F = 10A, T _J = 125°C		-	0.70	V
	MBRS2090CT MBRS20100CT	, , ,		-	0.75	V
	MBRS20150CT			-	0.87	V
	MBRS2035CT MBRS2045CT			-	0.72	V
	MBRS2050CT MBRS2060CT	I _F = 20A, T _J = 125°C		-	0.85	V
	MBRS2090CT MBRS20100CT	. , ,		-	0.85	V
	MBRS20150CT			-	1.10	V



ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Reverse current @ rated V_{R}	MBRS2035CT MBRS2045CT MBRS2050CT MBRS2060CT MBRS2090CT MBRS20100CT MBRS20150CT	T _J = 25°C		-	100	μА
per diode ⁽²⁾	MBRS2035CT MBRS2045CT	T _J = 125°C	l _R	-	15	mA
	MBRS2050CT MBRS2060CT			-	10	mA
	MBRS2090CT MBRS20100CT MBRS20150CT			-	5	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE(1)	PACKAGE	PACKING
MBRS20xCT	TO-263AB (D ² PAK)	800 / Tape & Reel

Notes:

1. "x" defines voltage from 35V(MBRS2035CT) to 150V(MBRS20150CT)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

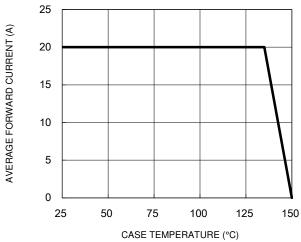


Fig.2 Typical Junction Capacitance

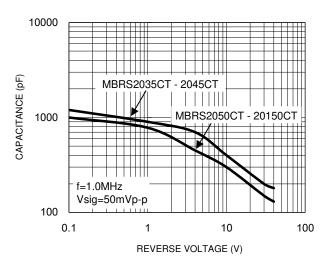
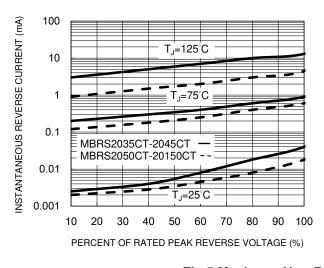


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



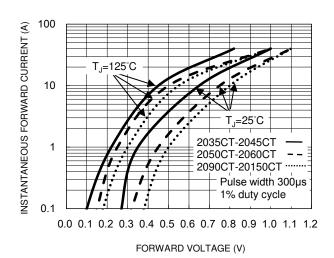
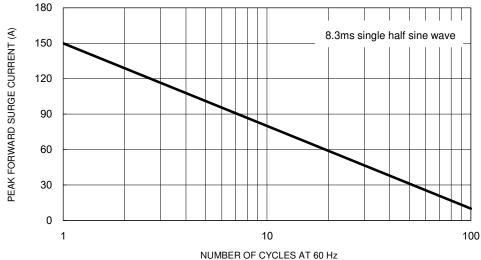


Fig.5 Maximum Non-Repetitive Forward Surge Current



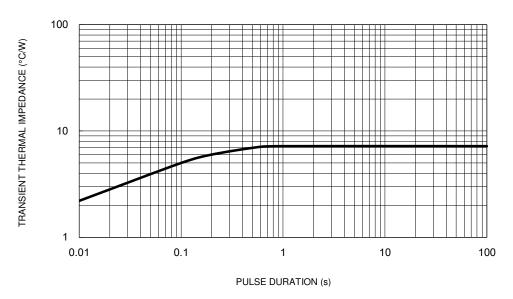
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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

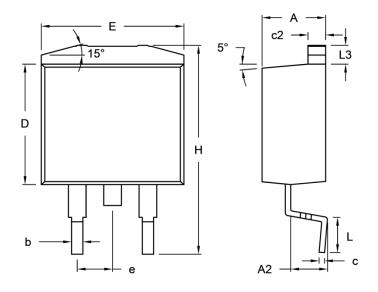
Fig.6 Typical Transient Thermal Impedance





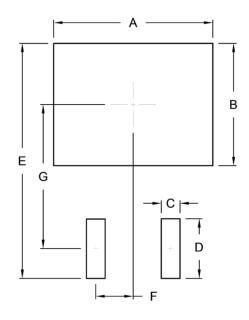
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM	DIM. Unit (mm)		Unit ((inch)	
DIM.	Min.	Max.	Min.	Max.	
Α	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
С	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
Н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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